## THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Gerrit Jan Hemink

Title:

Self-Boosting System for Flash Memory Cells

Application No.:

10/774,014

Filing Date:

February 6, 2004

Examiner:

Unassigned

Group Art Unit:

2827

Docket No.:

SNDK.327US0

Conf. No.:

8419

## Certificate of Mailing Under 37 CFR 1.8

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on March 28, 2005

Signature 5. Breeze

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicant calls the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application.

This application has a filing date after June 30, 2003. Therefore copies of the U.S. Patent and U.S. Published Patent Application documents listed on the accompanying Form PTO-1449 are not enclosed.

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a

Attorney Docket No.: SNDK.327US0

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representation that a search has been made (other than as indicated by any cited document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

This information disclosure statement is submitted under 37 C.F.R. § 1.97(b) and consequently no fee should be required. The Commissioner is authorized, however, to charge any fee that may be required, or to credit any overpayment, against Deposit Account No. 502664. This form is being submitted in duplicate.

Respectfully submitted,

Gerald P. Parsons

March 28, 2005 Date

Reg. No. 24,486

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U.S. Depa	rtment of	Commerce, Patent a	and Trademark	Atty. Docket No.			Application No.		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				SNDK.327US0			10/774,014		
				Applicant(s)			Conf. No.		
10. FE	(Dige sev	eral sheets if necessa	ary)	Gerrit Jan Hemink			8419		
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	11	2003/0147278A1	8/7/2003	Tanaka et al.					
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citation if not in conformance and not considered. Include copy of this form with your communication to applicant.									